# Voltage references

Voltage references are blocks that produce an output voltage that is independent of **PVT** variations:

- **V:** Supply voltage
- **T:** Temperature
- **P:** Process errors

Voltage references are used for:

- •Providing an absolute reference voltage for ADCs and DACs
- $\bullet$  Providing an absolute reference voltage for stimulating sensors or other external devices that require precise control voltages and/or currents.
- $\bullet$ Creating constant bias voltages (and currents) when required

# Possible reference voltage sources

•Zener Diodes



Problems:

- **Require additional process steps**, but only a small number of components are required for each chip (not convenient)
- **Available voltages are > 3 V**
- > Temperature stability is poor for V <sub>z</sub>≠ 5-6 V
- > The reference voltage generated by a Zener diode is noisy (very wide band noise)
- •Band-gap circuits

Band-gap voltage reference: principle of operation



P. Bruschi – Microelectronic System Design $n \frac{3}{2}$ 

### Band-gap voltage reference: determination of parameter  $\bm{b}$ and estimate of the output voltage



P. Bruschi – Microelectronic System Design



P. Bruschi – Microelectronic System Design $n \hspace{1.5cm}$ 

## Band-Gap voltage reference: theory

$$
V_{BE} = V_{GO} + V_{T} \left[ \ln(G \cdot E) - (\gamma - \alpha) \ln(T) \right]
$$
  
\n
$$
V_{BG} = V_{GO} + V_{T} \left[ \ln(G \cdot E) + b - (\gamma - \alpha) \ln(T) \right]
$$
  
\n
$$
V_{BG} = \frac{E_{g0}}{q}
$$
  
\n
$$
V_{GO} \text{ is numerically}
$$
  
\n
$$
V_{GO} \text{ is numerically}
$$
  
\n
$$
V_{GO} = \frac{V_{GO}}{q}
$$
  
\n
$$
V_{GO} \text{ is numerically}
$$
  
\n
$$
V_{GO} = \frac{V_{GO}}{q}
$$
  
\n
$$
V_{GO} \text{ is numerically}
$$
  
\n
$$
V_{GO} = \frac{V_{GO}}{q}
$$
  
\n
$$
V_{GO} = 1.2 \text{ V}
$$
  
\n
$$
V_{GO} \text{ is numerically}
$$
  
\n
$$
V_{GO} = 1.2 \text{ V}
$$
  
\n
$$
\frac{dV_{BG}}{dT} = \frac{k}{q} \left[ \ln(G \cdot E) + b - (\gamma - \alpha) \ln(T) \right] - (\gamma - \alpha) \left[ \frac{V_{T}}{T} \right] - \frac{k}{q}
$$
  
\nThe derivative of  $V_{OC}$  depends

$$
\frac{dV_{BG}}{dT} = \frac{k}{q} \Big[ \ln (G \cdot E) + b - (\gamma - \alpha) - (\gamma - \alpha) \ln (T) \Big]
$$

The derivative of  $V_{BG}$  $\sigma_G$  depends on temperature

P. Bruschi – Microelectronic System Design $n \t\t 6$  Band-Gap voltage reference: theory



P. Bruschi – Microelectronic System Design $n \hspace{1.5cm}$ 



P. Bruschi – Microelectronic System Design $n \hspace{1.5cm}$ <sup>8</sup>



P. Bruschi – Microelectronic System Design $n \qquad \qquad ^{9}$ 

### Band-Gap voltage: a CMOS compatible Circuit



P. Bruschi – Microelectronic System Design $\mathsf{n}$  10

## Deriving a temperature sensor from the Band-Gap circuit



Adding this branch, we can obtain a voltage proportional to the absolute temperature, which can be conveniently used to monitor the chip temperature.

$$
V_{Temp} = R_3 I = \frac{R_3}{R_1} \frac{kT}{q} \ln(n)
$$

P. Bruschi – Microelectronic System Design $\mathsf{n}$  11

## PTAT current generator: multiple stable states



**A start-up** circuit is necessary to prevent the circuit from being trapped into P2

P. Bruschi – Microelectronic System Design



P. Bruschi – Microelectronic System Design